20A, 45V Schottky Barrier Rectifier

FEATURES

TAIWAN

• AEC-Q101 qualified available

SEMICONDUCTOR

- Low forward voltage drop
- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converter

MECHANICAL DATA

- Case: R-6
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 1.60g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I _F	20	А
V _{RRM}	45	V
I _{FSM}	275	А
T _{J MAX}	200	°C
Package	R-6	
Configuration	Single die	



R-6

Anode

Cathode

PARAMETER	SYMBOL	SK20H45	UNIT
Marking code on the device		SK20H45	
Repetitive peak reverse voltage	V _{RRM}	45	V
Reverse voltage, total rms value	V _{R(RMS)}	31	V
Forward current	I _F	20	Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	275	А
Junction temperature in the DC forward mode	TJ	-55 to +200	°C
Storage temperature	T _{STG}	-55 to +175	°C



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-lead thermal resistance	R _{eJL}	6	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^{\circ}C$ unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage ⁽¹⁾	$I_F = 20A, T_J = 25^{\circ}C$	V _F	-	0.55	V
Reverse current @ rated $V_R^{(2)}$	$T_J = 25^{\circ}C$	I	-	500	μA
	$T_J = 100^{\circ}C$	IR IR	-	50	mA

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

RDERING INFORMATION			
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING	
SK20H45	R-6	1,000 / Tape & Reel	
SK20H45 A0G	R-6	700 / Ammo box	
SK20H45H	R-6	1,000 / Tape & Reel	
SK20H45HA0G	R-6	700 / Ammo box	

Notes:

1. "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$



Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics



10000



Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics





PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit ((inch)
	Min.	Max.	Min.	Max.
А	25.40	-	1.000	-
В	8.60	9.10	0.339	0.358
С	1.20	1.30	0.047	0.051
D	6.80	7.20	0.268	0.283

MARKING DIAGRAM



= Marking Code
= Green Compound
= Date Code
= Factory Code



Taiwan Semiconductor

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